DIODES
INCORPORATED

Lead-free Green

DMC3025LDV

COMPLEMENTARY PAIR ENHANCEMENT MODE MOSFET
POWERDI

Product Summary

Device	BV$_{DSS}$	R$_{DS(ON)}$ max	I$_D$ max T$_C$ = +25°C
Q1	30V	25mΩ @ V$_{GS}$ = 10V	15A
		35mΩ @ V$_{GS}$ = 4.5V	12.5A
Q2	-30V	25mΩ @ V$_{GS}$ = -10V	-15A
		38mΩ @ V$_{GS}$ = -4.5V	-12A

Description

This new generation MOSFET is designed to minimize the on-state resistance (R$_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Power Management Functions
- Analog Switch

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Complementary Pair MOSFET
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Mechanical Data

- Case: PowerDI3333-8 (Type UXC)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish — Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
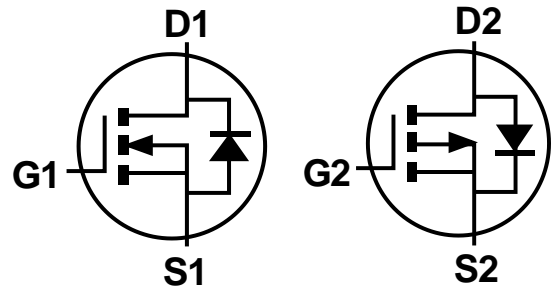- Weight: 0.072 grams (Approximate)

PowerDI3333-8 (Type UXC)
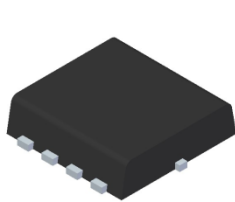
Top View
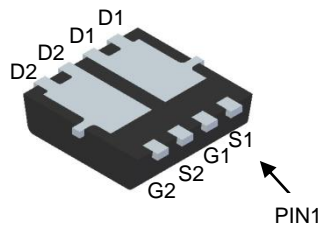
Bottom View

Equivalent Circuit

N-Channel MOSFET

P-Channel MOSFET

Ordering Information (Note 4)

Part Number	Case	Packaging
DMC3025LDV-7	PowerDI3333-8 (Type UXC)	2000/Tape & Reel
DMC3025LDV-13	PowerDI3333-8 (Type UXC)	3000/Tape & Reel

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information
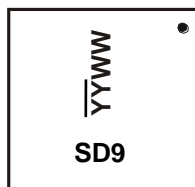
SD9 = Product Type Marking Code
$\overline{YY}$WW = Date Code Marking
$\overline{YY}$ = Last Two Digits of Year (ex: 16 for 2016)
WW = Week Code (01 to 53)

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Maximum Ratings Q1 N-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current, V_{GS} = 10V (Note 7)	Steady State	T_C = +25°C T_C = +70°C	I_D	15 12	A
Maximum Body Diode Forward Current (Note 6)			I_S	2	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I_{DM}	55	A
Avalanche Current (L = 0.1mH) (Note 8)			I_{AS}	14	A
Avalanche Energy (L = 0.1mH) (Note 8)			E_{AS}	9.8	mJ

Maximum Ratings Q2 P-CHANNEL (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current, V_{GS} = -10V (Note 7)	Steady State	T_C = +25°C T_C = +70°C	I_D	-15 -12	A
Maximum Body Diode Forward Current (Note 6)			I_S	-2	A
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)			I_{DM}	-45	A
Avalanche Current (L = 0.1mH) (Note 8)			I_{AS}	-22	A
Avalanche Energy (L = 0.1mH) (Note 8)			E_{AS}	24	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P_D	1.0	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	119	°C/W
	t<10s		72	
Total Power Dissipation (Note 6)		P_D	1.9	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	66	°C/W
	t<10s		38	
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	15	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

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Electrical Characteristics N-CHANNEL – Q1 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV_{DSS}	30	–	–	V	V_{GS} = 0V, I_D = 250µA
Zero Gate Voltage Drain Current T_J = +25°C	I_{DSS}	–	–	1	µA	V_{DS} = 30V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	–	–	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	$V_{GS(TH)}$	1.0	–	2.0	V	V_{DS} = V_{GS}, I_D = 250µA
Static Drain-Source On-Resistance	$R_{DS(ON)}$	–	15	25	mΩ	V_{GS} = 10V, I_D = 7A
			24	35		V_{GS} = 4.5V, I_D = 7A
Diode Forward Voltage	V_{SD}	–	0.70	1.0	V	V_{GS} = 0V, I_S = 1A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C_{iss}	–	500	–	pF	V_{DS} = 15V, V_{GS} = 0V, f = 1.0MHz
Output Capacitance	C_{oss}	–	72	–		
Reverse Transfer Capacitance	C_{rss}	–	57	–		
Gate Resistance	R_G	–	1.9	–	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz
Total Gate Charge (V_{GS} = 4.5V)	Q_g	–	4.6	–	nC	V_{DS} = 15V, I_D = 10A
Total Gate Charge (V_{GS} = 10V)	Q_g	–	9.8	–		
Gate-Source Charge	Q_{gs}	–	1.6	–		
Gate-Drain Charge	Q_{gd}	–	2.0	–		
Turn-On Delay Time	$t_{D(ON)}$	–	3.9	–	ns	V_{DD} = 15V, V_{GS} = 10V, R_G = 6Ω, I_D = 1A
Turn-On Rise Time	t_R	–	4.2	–		
Turn-Off Delay Time	$t_{D(OFF)}$	–	16.6	–		
Turn-Off Fall Time	t_F	–	5.8	–		
Reverse Recovery Time	t_{RR}	–	5.6	–	ns	I_F = 12A, di/dt = 500A/µs
Reverse Recovery Charge	Q_{RR}	–	2.6	–	nC	

Electrical Characteristics P-CHANNEL – Q2 (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 9)						
Drain-Source Breakdown Voltage	BV_{DSS}	-30	–	–	V	V_{GS} = 0V, I_D = -250µA
Zero Gate Voltage Drain Current T_J = +25°C	I_{DSS}	–	–	-1	µA	V_{DS} = -30V, V_{GS} = 0V
Gate-Source Leakage	I_{GSS}	–	–	±100	nA	V_{GS} = ±20V, V_{DS} = 0V
ON CHARACTERISTICS (Note 9)						
Gate Threshold Voltage	$V_{GS(TH)}$	-1.2	–	-2.4	V	V_{DS} = V_{GS}, I_D = -250µA
Static Drain-Source On-Resistance	$R_{DS(ON)}$	–	21	25	mΩ	V_{GS} = -10V, I_D = -7A
			31	38		V_{GS} = -4.5V, I_D = -6.2A
Diode Forward Voltage	V_{SD}	–	-0.7	-1.2	V	V_{GS} = 0V, I_S = -2.1A
DYNAMIC CHARACTERISTICS (Note 10)						
Input Capacitance	C_{iss}	–	1,188	–	pF	V_{DS} = -15V, V_{GS} = 0V, f = 1MHz
Output Capacitance	C_{oss}	–	154	–		
Reverse Transfer Capacitance	C_{rss}	–	116	–		
Gate Resistance	R_G	–	9	–	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge (V_{GS} = -4.5V)	Q_g	–	9.5	–	nC	V_{DS} = -15V, I_D = -7A
Total Gate Charge (V_{GS} = -10V)	Q_g	–	19.7	–		
Gate-Source Charge	Q_{gs}	–	3.1	–		
Gate-Drain Charge	Q_{gd}	–	3.2	–		
Turn-On Delay Time	$t_{D(ON)}$	–	3.7	–	ns	V_{GS} = -10V, V_{DS} = -15V, R_G = 6Ω, I_D = -7A
Turn-On Rise Time	t_R	–	2.6	–		
Turn-Off Delay Time	$t_{D(OFF)}$	–	36	–		
Turn-Off Fall Time	t_F	–	22	–		
Reverse Recovery Time	t_{RR}	–	10.4	–	ns	I_F = -7A, di/dt = 100A/µs
Reverse Recovery Charge	Q_{RR}	–	3.2	–	nC	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Thermal resistance from junction to soldering point (on the exposed drain pad).
8. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.
9. Short duration pulse test used to minimize self-heating effect.
10. Guaranteed by design. Not subject to product testing.

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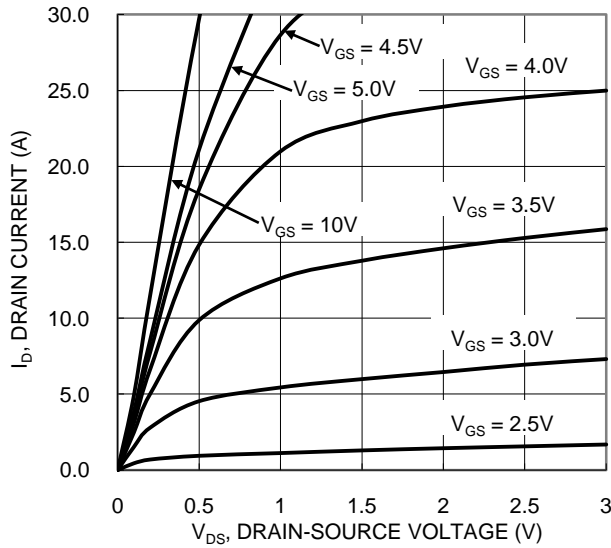## Typical Characteristics - N-CHANNEL
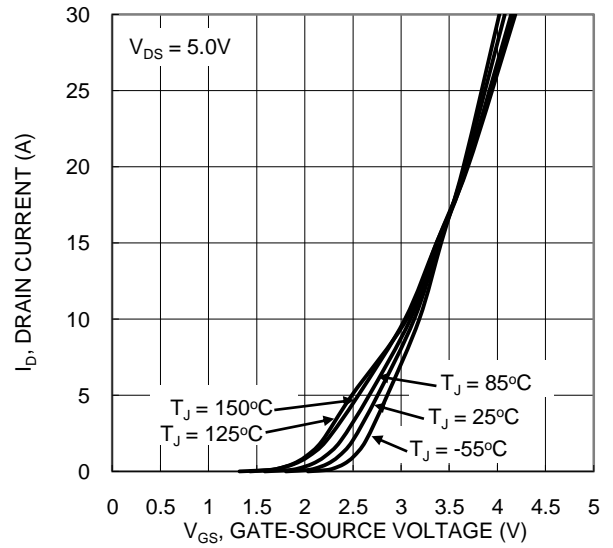

Figure 1. Typical Output Characteristic

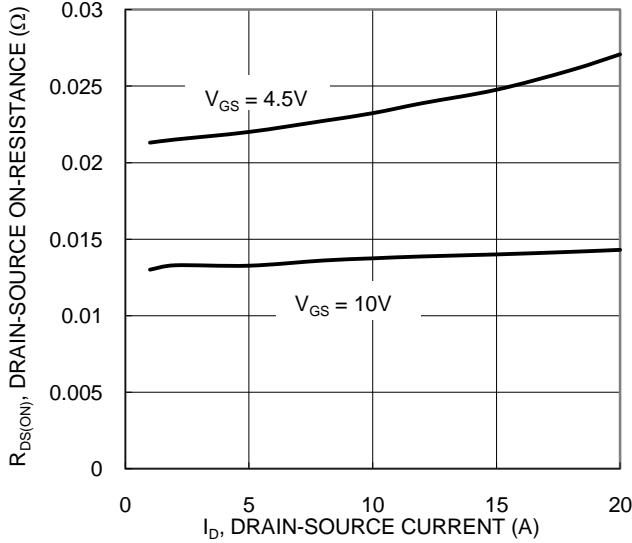Figure 2. Typical Transfer Characteristic

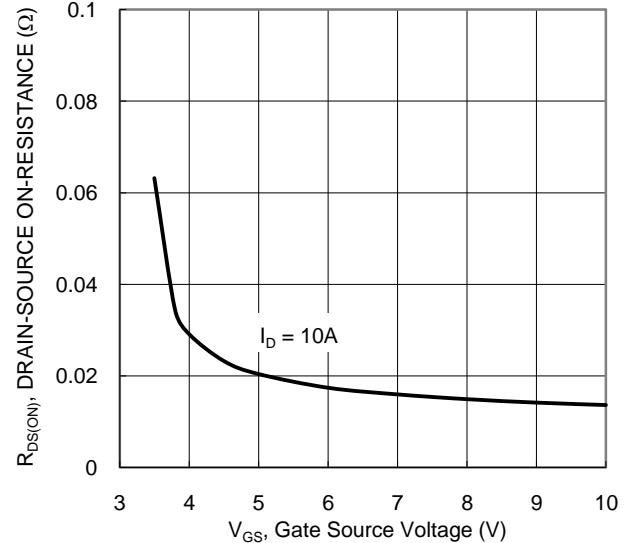Figure 3. Typical On-Resistance vs Drain Current and Gate Voltage

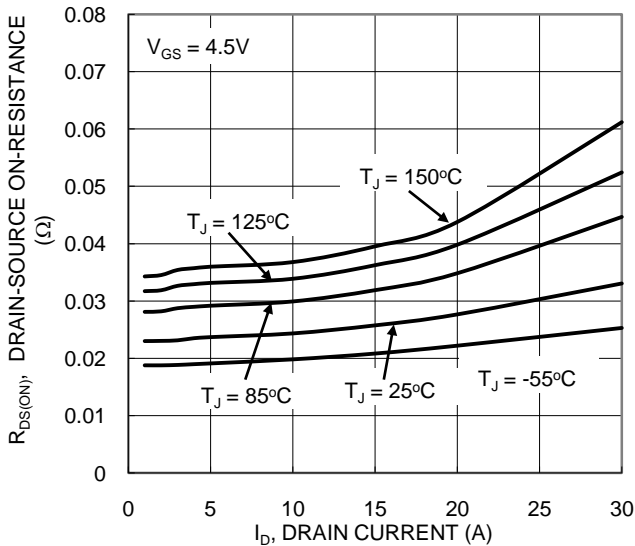Figure 4. Typical On-Resistance vs Drain Current and Gate Voltage

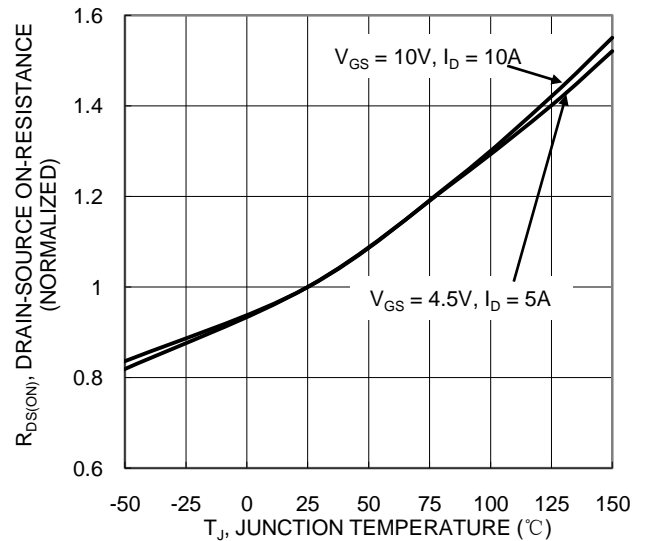Figure 5. Typical On-Resistance vs Drain Current and Temperature

Figure 6. On-Resistance Variation with Temperature

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Typical Characteristics - N-CHANNEL (Cont.)
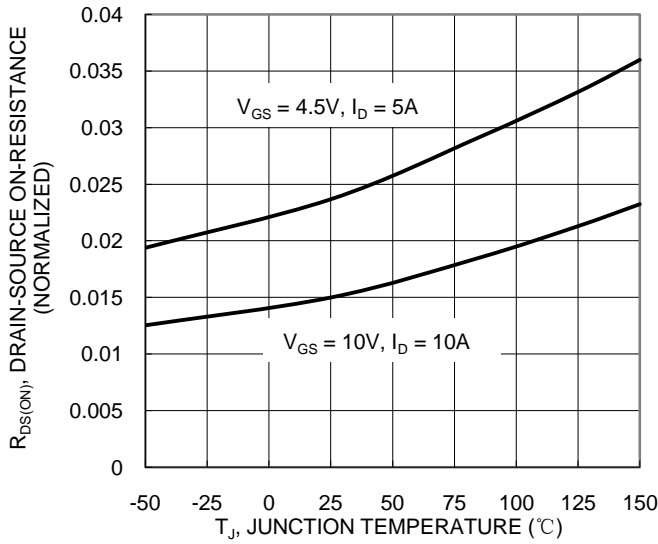
Figure 7. On-Resistance Variation with Temperature

Plot axes: $R_{DS(ON)}$, DRAIN-SOURCE ON-RESISTANCE (NORMALIZED) vs T_J, JUNCTION TEMPERATURE (℃). Curves labeled V_{GS} = 4.5V, I_D = 5A and V_{GS} = 10V, I_D = 10A.
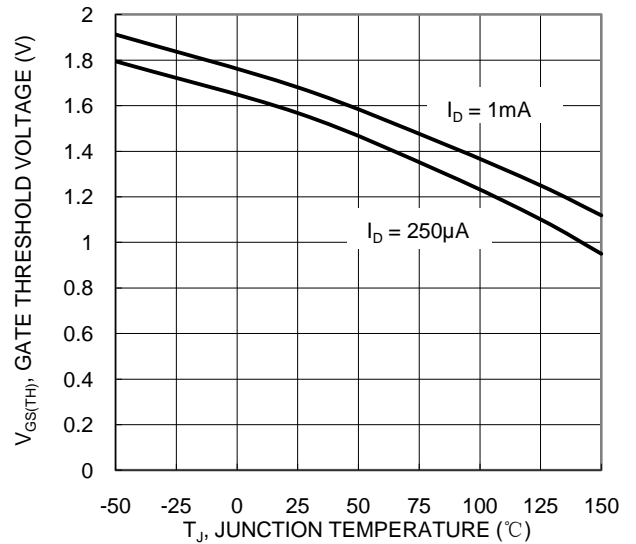
Figure 8. Gate Threshold Variation vs Junction Temperature

Plot axes: $V_{GS(TH)}$, GATE THRESHOLD VOLTAGE (V) vs T_J, JUNCTION TEMPERATURE (℃). Curves labeled I_D = 1mA and I_D = 250µA.
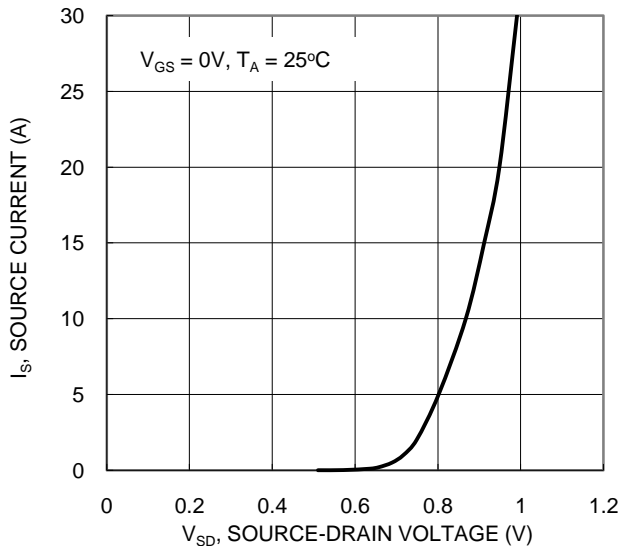
Figure 9. Diode Forward Voltage vs Current

Plot axes: I_S, SOURCE CURRENT (A) vs V_{SD}, SOURCE-DRAIN VOLTAGE (V). V_{GS} = 0V, T_A = 25℃.
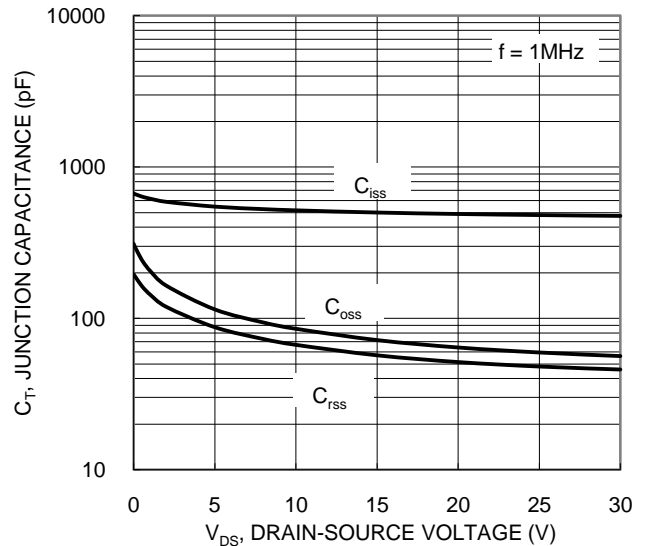
Figure 10. Typical Junction Capacitance

Plot axes: C_T, JUNCTION CAPACITANCE (pF) vs V_{DS}, DRAIN-SOURCE VOLTAGE (V). f = 1MHz. Curves labeled C_{iss}, C_{oss}, C_{rss}.

Figure 11. Gate Charge

Plot axes: V_{GS} (V) vs Q_g (nC). V_{DS} = 15V, I_D = 10A.
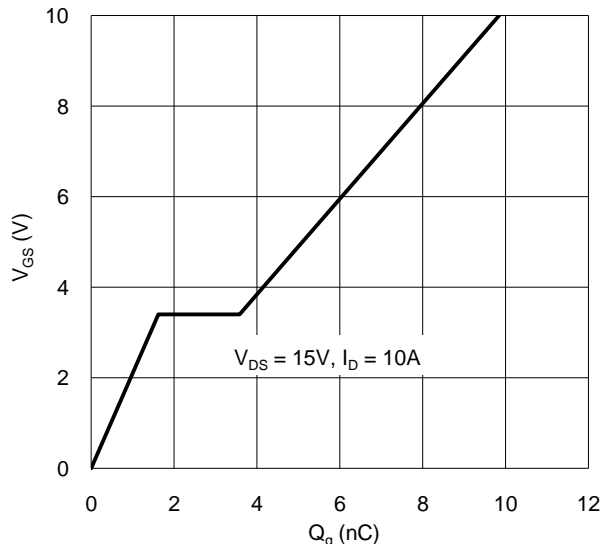
Figure 12. SOA, Safe Operation Area

Plot axes: I_D, DRAIN CURRENT (A) vs V_{DS}, DRAIN-SOURCE VOLTAGE (V). Curves labeled $R_{DS(ON)}$ Limited, P_W = 1ms, P_W = 100µs, DC, P_W = 10s, P_W = 1s, P_W = 100ms, P_W = 10ms. $T_{J(Max)}$ = 150℃, T_C = 25℃, Single Pulse, DUT on 1*MRP Board, V_{GS} = 10V.

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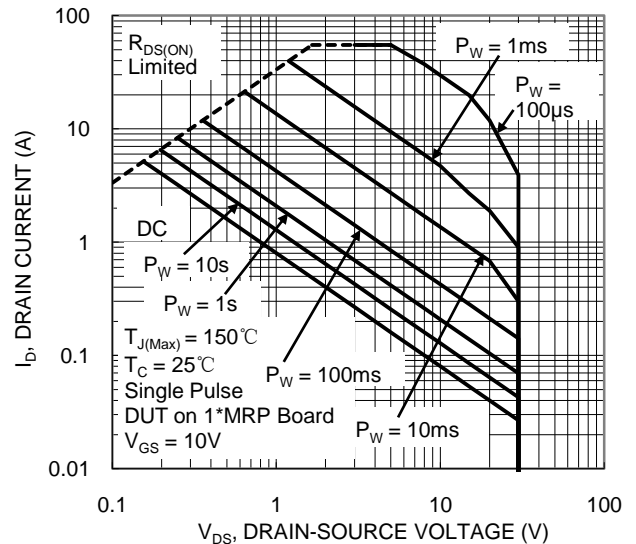© Diodes Incorporated
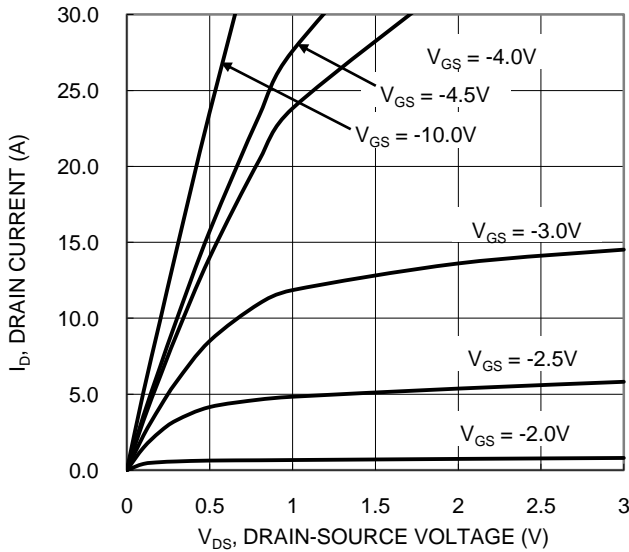
Typical Characteristics - P-CHANNEL

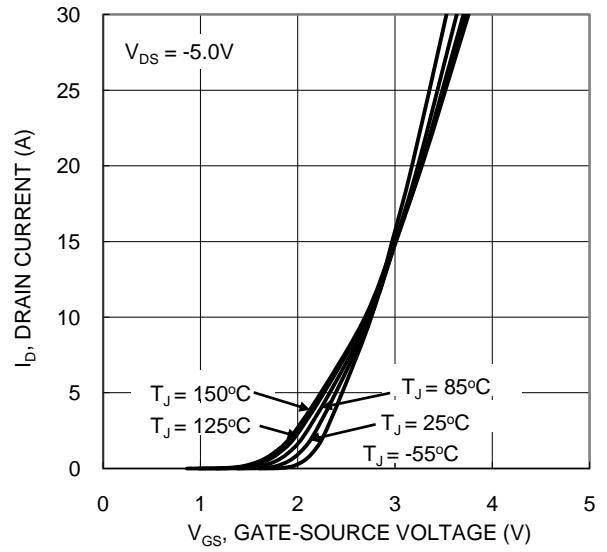Figure 13. Typical Output Characteristic
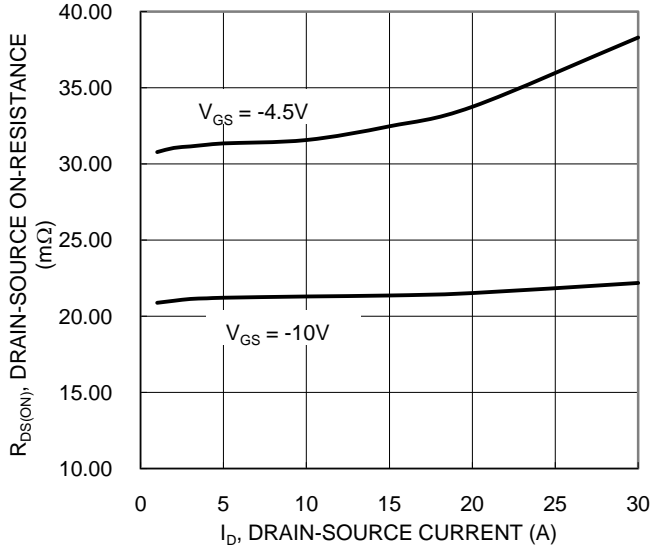

Figure 14. Typical Transfer Characteristic

Figure 15. Typical On-Resistance vs Drain Current
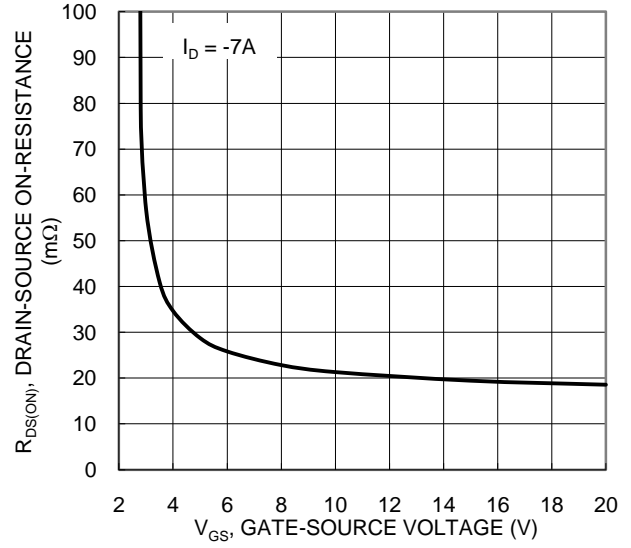and Gate Voltage

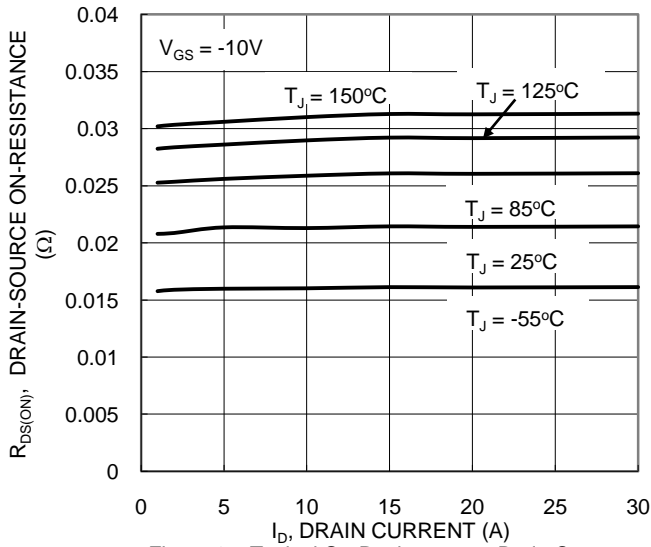Figure 16. Typical Transfer Characteristic

Figure 17. Typical On-Resistance vs Drain Current
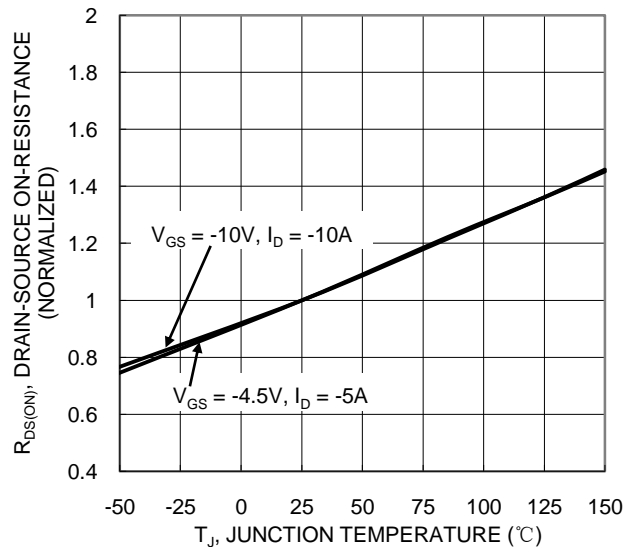and Temperature

Figure 18. On-Resistance Variation with Temperature

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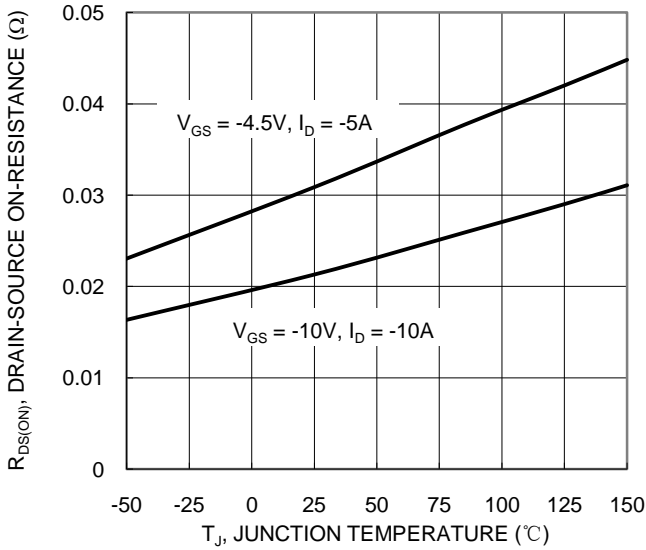## Typical Characteristics - P-CHANNEL (Cont.)

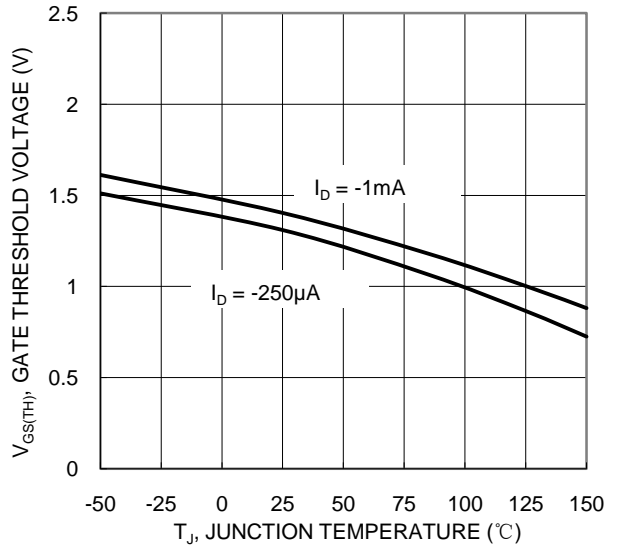Figure 19. On-Resistance Variation with Temperature

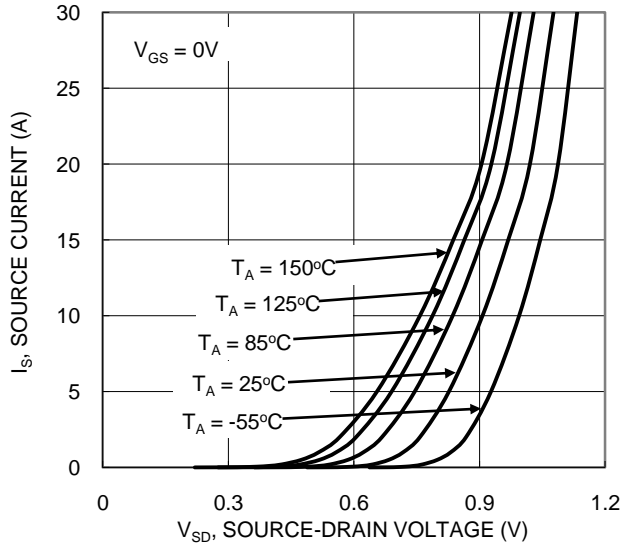Figure 20. Gate Threshold Variation vs Junction Temperature

Figure 21. Diode Forward Voltage vs. Current
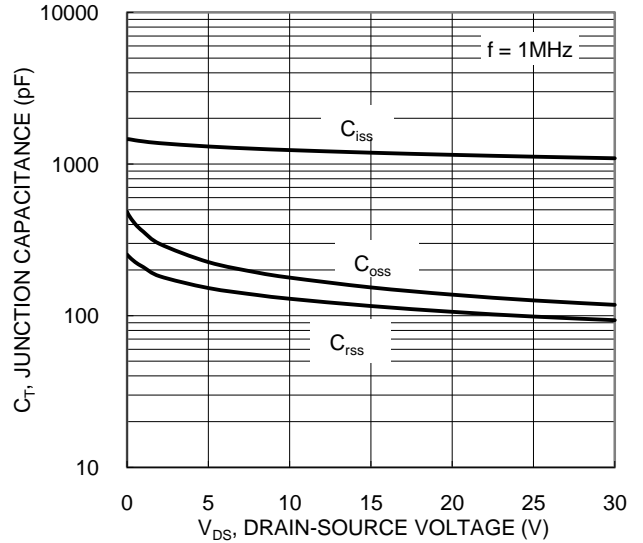
Figure 22. Typical Junction Capacitance
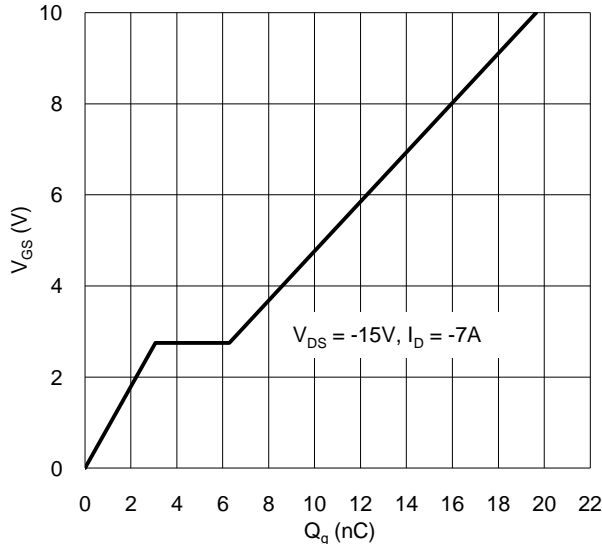
Figure 23. Gate Charge
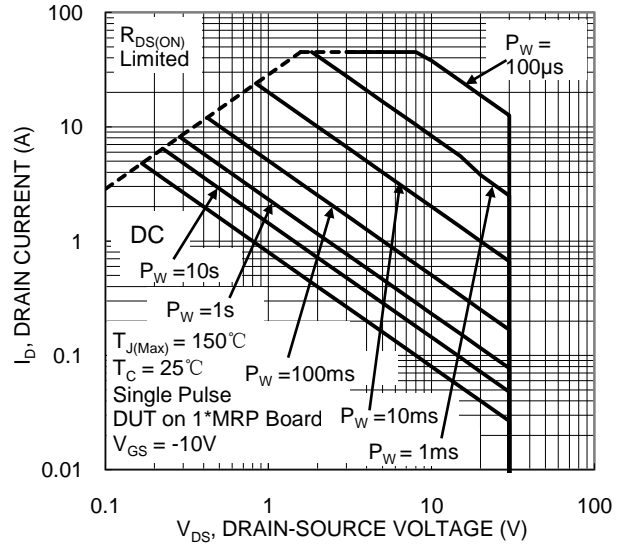
Figure 24. SOA, Safe Operation Area

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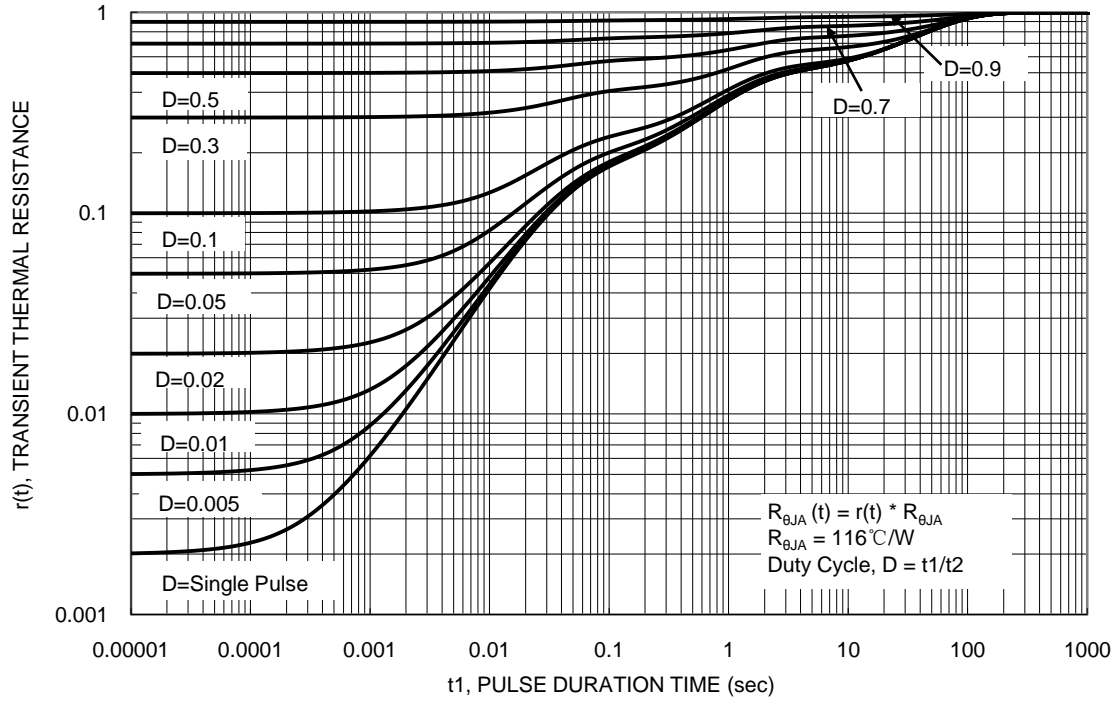
Figure 25. Transient Thermal Resistance

The figure shows a log-log plot of r(t), TRANSIENT THERMAL RESISTANCE (y-axis, from 0.001 to 1) versus t1, PULSE DURATION TIME (sec) (x-axis, from 0.00001 to 1000). Curves are labeled for various duty cycles: D=0.9, D=0.7, D=0.5, D=0.3, D=0.1, D=0.05, D=0.02, D=0.01, D=0.005, and D=Single Pulse.

$R_{\theta JA}(t) = r(t) * R_{\theta JA}$
$R_{\theta JA} = 116\,°C/W$
Duty Cycle, $D = t1/t2$

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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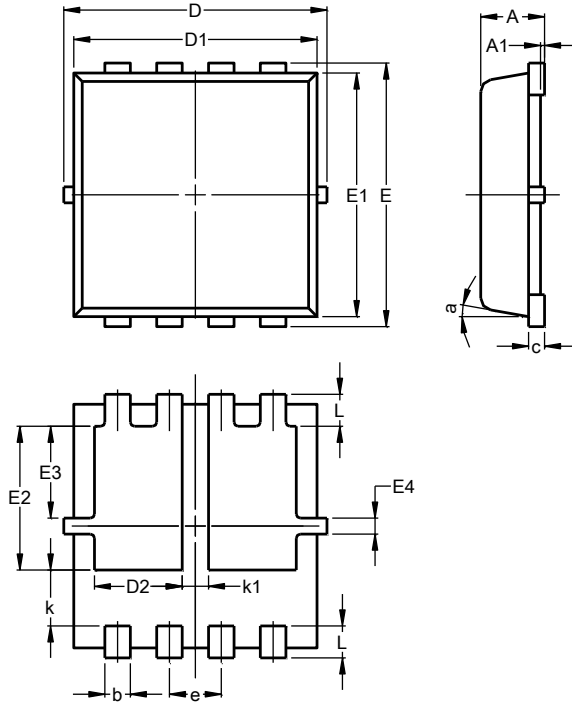
PowerDI3333-8 (Type UXC)			
Dim	**Min**	**Max**	**Typ**
A	0.75	0.85	0.80
A1	0.00	0.05	--
b	0.25	0.40	0.32
c	0.10	0.25	0.15
D	3.20	3.40	3.30
D1	2.95	3.15	3.05
D2	0.90	1.30	1.10
E	3.20	3.40	3.30
E1	2.95	3.15	3.05
E2	1.60	2.00	1.80
E3	0.95	1.35	1.15
E4	0.10	0.30	0.20
e	–	–	0.65
L	0.30	0.50	0.40
k	0.50	0.90	0.70
k1	0.13	0.53	0.33
a	0°	12°	10°
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UXC)
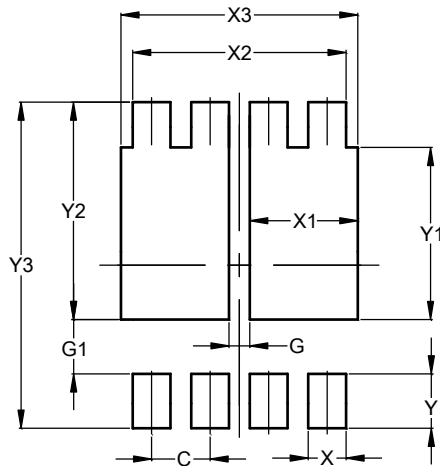
Dimensions	Value (in mm)
C	0.650
G	0.230
G1	0.600
X	0.420
X1	1.200
X2	2.370
X3	2.630
Y	0.600
Y1	1.900
Y2	2.400
Y3	3.600

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A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or

2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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